

Device Material Content

5555 NE Moore Ct.							
Hillsboro OR 97124	Package:		100 TQFP (1.4mm)		with matte Sn Plating	Copper Bond Wire Version	
custreq@lscc.com	Tota	l Device Weight	0.65	Grams			Halogen Free
							MSL: 3 - Peak Reflow Temp: 260°C
August, 2012	% of Total Pkg. Wt.	Weight (g)	% of Total Pkg. Wt.	Weight (g)	Substance	CAS#	Notes / Assumptions:
Die	3.61%	0.0234			Silicon chip	7440-21-3	Die size: 4.30 x 6.50 mm
Mold	74.68%	0.4854	63.48% 4.48% 3.73% 0.30% 2.69%	0.4126 0.0291 0.0243 0.0019 0.0175	Silica Fused Epoxy Resin Phenol Resin Other (trade secret) Carbon black	60676-86-0 - - - 1333-86-4	Mold Compound Density between 1.87 and 2.17 grams/cc 82 to 94% Silica Fused (LSC uses 86.8% in our calculation) 1.5 to 11% Epoxy Resin (LSC uses 8% in our calculation). 3 to 6% Phenol Resin (LSC uses 4% in our calculation). 2% (max) Other (LSC uses 1% in our calculation) 0.2% (typical) Carbon black (LSC uses 0.2% in our calculation)
D/A Epoxy	0.44%	0.0028	0.35% 0.09%	0.0023 0.0006	Silver (Ag) other	7440-22-4	Die attach epoxy Density: 3 grams/cc (silver content: 70-90%; LSC uses 80% in our calculation)
Wire	0.21%	0.0014			Copper (Cu)	7440-50-8	0.8 mil wire diameter; 1 wire for each package lead; wire length 3 mm
Lead Plating	1.83%	0.0119			Tin (Sn)	7440-31-5	Plating is 100% Sn; thickness is 0.015mm
Leadframe	19.23%	0.1250	18.50% 0.577% 0.125% 0.029%	0.1203 0.0038 0.00081 0.00019	Copper (Cu) Nickel (Ni) Silicon (Si) Magnesium (Mg)	7440-50-8 7440-02-0 7440-21-3 7439-95-4	Leadframe thickness is nominal (per Case Outline) Cu 96.2% Ni 3.0% Si 0.65% Mg 0.15% Copper area is fixed at 50% package area

Notes:

The values listed above are nominal values based on studies of representatives of this particular package type, and are believed to be as accurate as possible. Constituent substances and proportions in epoxy materials are before curing.

The information provided above is representative of the package as of the date listed, and is subject to change at any time.

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